

Vishay Semiconductors

ADD-A-PAK Generation VII Power Modules Schottky Rectifier, 200 A



PRODUCT SUMMARY		
I _{F(AV)}	200 A	

MECHANICAL DESCRIPTION

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation
- · Low thermal resistance
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for industrial level

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- · Easy mounting on heatsink

ELECTRICAL DESCRIPTION

The VSKDS409/150 Schottky rectifier doubler module has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	200	A			
V _{RRM}		150	V			
I _{FSM}	t _p = 5 µs sine	20 000	A			
V _F	200 Apk, T _J = 125 °C	0.85	V			
T _J	Range	- 55 to 175	°C			

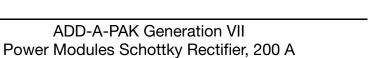
VOLTAGE RATINGS				
PARAMETER	SYMBOL	VSKDS409/150	UNITS	
Maximum DC reverse voltage	V_{R}	150	V	
Maximum static peak reverse voltage	V _{RRM}	150	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _C = 105 °C, rectangular waveform		200	
Maximum peak one cycle	I _{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	20 000	Α
non-repetitive surge current		10 ms sine or 6 ms rect. pulse		2300	
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1.8 \text{A}, L = 10 \text{mH}$		15	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1	А
Maximum dynamic peak reverse voltage	V _{AV}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1.8 \text{A}, L = 10 \text{mH}$		170	V

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VSKDS409/150

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Marian markania dia mandra dia ma		200 A	T _J = 25 °C	1.03	V
		400 A		1.33	
Maximum forward voltage drop	V _{FM}	200 A	T _J = 125 °C	0.85	
		400 A		1.13	
Marinana	I _{RM}	T _J = 25 °C	V _R = Rated V _R	6	mA
Maximum reverse leakage current		T _J = 125 °C		85	IIIA
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		6000	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		5.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs
Maximum RMS insulation voltage	V _{INS}	50 Hz		3000 (1 min) 3600 (1 s)	V

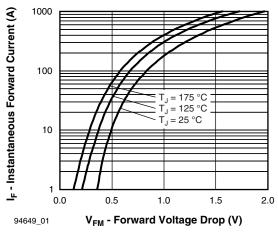
THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	е	T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	0.32	°C/W
Typical thermal resistance, case to heatsink per module		R _{thCS}		0.1	
Approximate weight				75	g
Approximate weight				2.7	oz.
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the	4	Nm
	busbar		spread of the compound.	3	INIII
Case style			JEDEC	TO-240AA co	ompatible

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1000 = 175 °C I_R - Reverse Current (mA) 100 T_J = 125 °C 10 = 100 °C 0.1 0.01 0.001 75 100 125 150 V_R - Reverse Voltage (V) 94649_02

Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

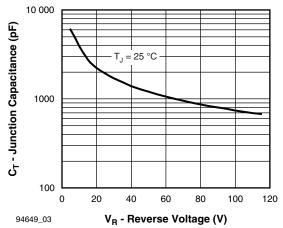


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

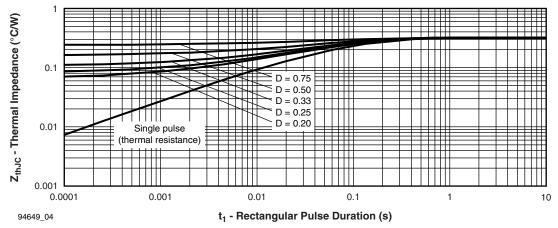


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Diode)

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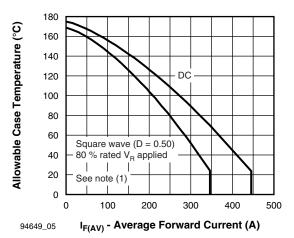


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

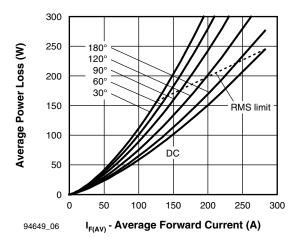


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

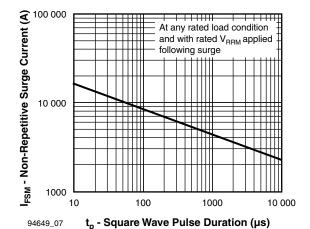


Fig. 7 - Maximum Non-Repetitive Surge Current

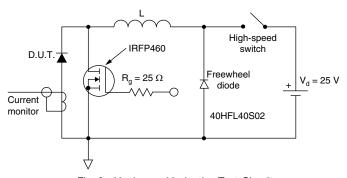


Fig. 8 - Unclamped Inductive Test Circuit

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; Pd = Forward power loss = $I_{F(AV)}$ x V_{FM} at ($I_{F(AV)}$ /D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

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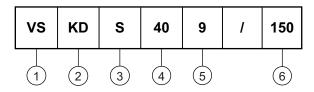


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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Circuit configuration:

KD = ADD-A-PAK - 2 diodes in series

3 - S = Schottky diode

Average current rating (40 = 400 A) (1)

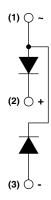
5 - Product silicon identification

6 - Voltage rating (150 = 150 V)

Note

 $^{(1)}$ For KD configuration average current rating per module is 200 A

CIRCUIT CONFIGURATION



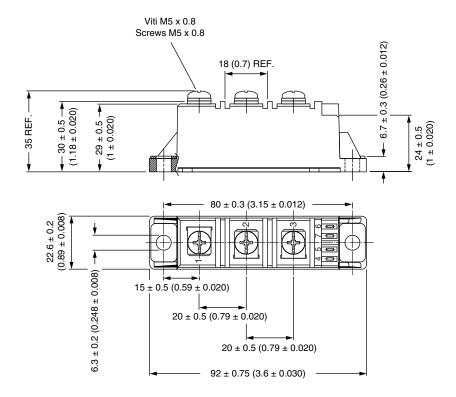
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95369		



Vishay Semiconductors

ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)







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